

U.S. PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | . Name | Classification |
|---|----|---|-----------------|--------|----------------|
| | Α | US- | | | |
| | В | US- | | | |
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| | D | US- | | | |
| | Е | US- | - | | |
| | F | US- | | | |
| | G | US- | | | |
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| | # | US- | | | |
| | J | US- | | | |
| | К | US- | | | |
| | L | US- | | | |
| | М | US- | | | |

FOREIGN PATENT DOCUMENTS

| * | | Document Number Country Code-Number-Kind Code | Date MM-YYYY | Country | Name | Classification |
|---|---|--|-----------------|---------|---------------|----------------|
| | N | JP11354840 | 12-1999 | JPO | Tanaka et al. | |
| | 0 | JP11354839 | 12-1999 | JPO | Tanaka et al. | |
| | Р | | | | | |
| | Q | | | | | |
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NON-PATENT DOCUMENTS

| * | <u> </u> | Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages) | | | | | |
|---|----------|--|--|--|--|--|--|
| | U | Tanaka et al. "GaN Quantum structures with Fractional Dimension From Quantum Well o Quantum Dot," phys. stat sol. (b) 216 481, 1999 | | | | | |
| | V | Tanaka et al, "Anti Surfactant in III-Nitride Epitaxy-Quantum Dot Formation and dislocation Termination," Japanese Journal of Appiled Physics, Vol 39 8b, 2000 | | | | | |
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A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.